

ECE228B
Fiber Optic Components and Systems
Homework #2 Solutions

Problem 1:

Consider a 1.55 μm InGaAsP /InP bulk laser 400 μm in length with confinement factor $\Gamma=.05$, internal quantum efficiency of 80% and internal loss of 10 cm^{-1} . cleaved facets, 0.2 mm thick active region, 0.1 ps lifetime for the linewidth calculation.

- a. Plot the gain versus wavelength
- b. Plot the peak gain versus carrier density
- c. What is the mirror loss?

$$\alpha_m = \frac{1}{L} \ln\left(\frac{1}{R}\right) = \frac{1}{.04\text{cm}} \ln\left(\frac{1}{.32}\right) = 28.46 \text{ cm}^{-1}$$

- d. What is the threshold modal gain?

$$\begin{aligned}\Gamma g_{th} &= \alpha_{Total} \\ \alpha_{Total} &= \alpha_i + \alpha_m = 10.00 \text{ cm}^{-1} + 28.46 \text{ cm}^{-1} = 38.46 \text{ cm}^{-1} \\ g_{th} &= \frac{\alpha_{Total}}{\Gamma} = \frac{38.46 \text{ cm}^{-1}}{.05} = 769.2 \text{ cm}^{-1}\end{aligned}$$

- e. What is the differential quantum efficiency?

$$\eta = \frac{\eta_i \alpha_m}{\alpha_i} = \frac{(0.8)28.46}{38.46} = 0.59$$

- f. What is the axial mode spacing?
Assume $N_g = 3.5$

$$\Delta\lambda = \frac{\lambda^2}{2n_g L} = \frac{(1.55)^2}{(2)(3.5)(400 \times 10^{-4})} = 0.85 \text{ nm}$$

Problem 2:

Consider a DFB laser with a 400 μm long grating, an effective mode index 3.5 and a grating corrugation period 0.22 μm . Calculate the symmetric modes (wavelengths) that the laser will operate at assuming no $\lambda/4$ phase shift in the grating. What will be the output wavelength if the grating is fabricated with a $\lambda/4$ phase shift in the grating?

For DFB with $\lambda/4$ shift, single mode will operate at $\Delta\beta L = 0$, which gives

$$\lambda = 2 n_{\text{eff}} \Lambda = 2 \times 3.5 \times 0.22 \mu\text{m} = 1.54 \mu\text{m}.$$

For DFB without $\lambda/4$ shift, there will be two modes, and $\Delta\beta L$ depends on κL .

$$\text{If } \kappa L = 1, \text{ then } \Delta\beta L = \pm 2.5, \quad \Delta\beta = \pm \frac{2.5}{400 \mu\text{m}} = \pm 0.0063 \mu\text{m}^{-1}.$$

$$\beta = \beta_0 \pm \Delta\beta = \frac{2\pi}{1.54 \mu\text{m}} \pm 0.0063 \mu\text{m}^{-1} = 4.0737 \mu\text{m}^{-1}, 4.0863 \mu\text{m}^{-1}.$$

$$\lambda = \frac{2\pi}{\beta} = 1.5424 \mu\text{m}, 1.5376 \mu\text{m}.$$

Problem 3:

Consider a ridge waveguide bulk InGaAsP /InP bulk laser with internal quantum efficiency of 80% and internal loss of 10 cm^{-1} , cleaved facets, 0.2 μm thick 1.55 μm composition active region, differential gain 2000 cm^{-1} and transparency carrier density of $2.8 \times 10^{18} \text{cm}^{-3}$. a) What is the transverse confinement factor? (use $n_a=3.5, n_c=3.17$) B) How many transverse modes exist? C) Assuming the structure below with a 200 μm cavity length, calculate the lateral confinement factor and threshold current as a function of the width of the waveguide. D) For a 2 μm waveguide width, plot the threshold current versus cavity length.

$$\eta_i = 80\%, \quad \langle \alpha_i \rangle = 10 \text{ cm}^{-1}, \quad d = 0.2 \mu\text{m}$$

$$g_0 = 2000 \text{ cm}^{-1}, \quad N_{tr} = 2.8 \times 10^{18} \text{ cm}^{-3}$$

$$a) \quad V = k_0 d \sqrt{n_a^2 - n_c^2} = \frac{2\pi}{1.55 \mu\text{m}} \times 0.2 \mu\text{m} \times \sqrt{3.5^2 - 3.17^2} = 1.20$$

$$\Gamma_x = \frac{V^2}{2+V^2} = 0.42$$

$$b) \quad \text{for } V = 1.20$$

there're only two modes, TE_0 and TM_0 .

c)

$$W = 2 \mu\text{m}$$

$$V_e = k_0 W \sqrt{n_a^2 - n_c^2} = \frac{2\pi}{1.55 \mu\text{m}} \times 2 \mu\text{m} \times \sqrt{3.5^2 - 3.17^2} = 12.0$$

$$\Gamma_y = \frac{V_e^2}{2 + V_e^2} = 0.99$$

$$I_{th} = \frac{B N_{tr}^2 \Gamma V}{\eta_i}$$

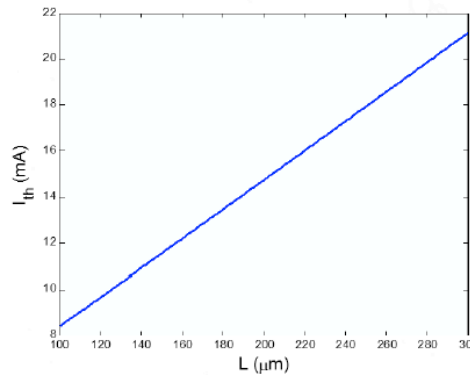
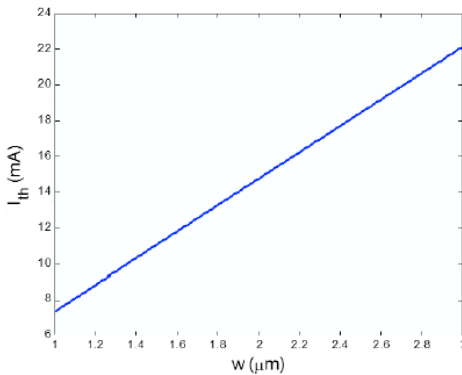
$$N_{tr} = N_{tr} e^{g_{th}/g_0} = N_{tr} e^{(\alpha_i + \alpha_m)/\Gamma g_0}$$

$$\Rightarrow I_{th} = \frac{\Gamma V B N_{tr}^2}{\eta_i} e^{2(\alpha_i + \alpha_m)/\Gamma g_0}$$

$$I_{th} = \frac{\int dW L B N_{tr}^2}{\eta_i} e^{2(\alpha_i + \alpha_m)/\Gamma g_0}$$

in which $B \sim 10^{-10} \text{ cm}^3/\text{s}$, $d = 0.2 \mu\text{m}$, $L = 200 \mu\text{m}$, $\eta_i = 0.8$,
 $N_{tr} = 2.8 \times 10^{18} \text{ cm}^{-3}$, $\alpha_i = 10 \text{ cm}^{-1}$, $\alpha_m = \frac{1}{L} \ln \frac{1}{R}$, $R = 0.32$,
 $\Gamma = \Gamma_x \Gamma_y \Gamma_z = 0.42$, $g_0 = 2000 \text{ cm}^{-1}$.

d) Same equation as in c), just make L the variable instead of w .



Problem 4:

Calculate and plot the wavelength shift vs. tuning current for a tunable Bragg reflector that operates based on the free-carrier plasma effect. Assume $\lambda_g = 1300 \text{ nm}$ InGaAsP tuning region operated at 1500 nm , $\beta_{pl} = -1.3 \times 10^{-20} \text{ cm}^3$, active region with $L = 400 \mu\text{m}$, $d = 0.3 \mu\text{m}$, $w = 2 \mu\text{m}$ and confinement factor $\Gamma_i = 0.3$. For the material assume an infinite spontaneous recombination time constant, bimolecular recombination constant $B = 10^{-10} \text{ cm}^3/\text{s}$ and Auger recombination constant $C = 3 \times 10^{-29} \text{ cm}^6/\text{s}$.

Active Volume $V = 400\mu\text{m} \times 2\mu\text{m} \times 0.3\mu\text{m}$
 $= 2.4 \times 10^{-10} \text{ cm}^3$

Current vs. carrier concentration is obtained from rate eqn.

$$\frac{I_g}{qV} = \beta N^2 + \alpha N^3$$

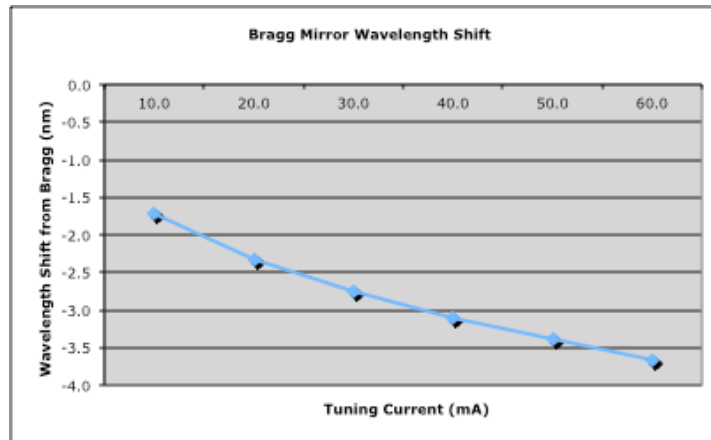
$$I_g = (1.6022 \times 10^{-19}) (2.4 \times 10^{-10}) \cdot [10^{-10} N^2 + 3 \times 10^{-29} N^3]$$

Solving for N for I_g from 0mA to 600mA

I_g (mA)	N	$\Delta\lambda$ (nm)
10	1.35×10^{18}	-1.7
20	1.83×10^{18}	-2.3
30	2.17×10^{18}	-2.8
40	2.45×10^{18}	-3.1
50	2.68×10^{18}	-3.4
60	2.89×10^{18}	-3.7

Using $\Delta\lambda = \frac{\beta_p d_g P_t N}{n_{\text{eff}}} = \frac{(-1.3 \times 10^{-20})(1300 \text{ nm})(0.3) N}{4}$

1.35E+18	-1.30E-20	1.30E-06	3.00E-01	4.00E+00	10.0	-1.7
1.83E+18	-1.30E-20	1.30E-06	3.00E-01	4.00E+00	20.0	-2.3
2.17E+18	-1.30E-20	1.30E-06	3.00E-01	4.00E+00	30.0	-2.8
2.45E+18	-1.30E-20	1.30E-06	3.00E-01	4.00E+00	40.0	-3.1
2.68E+18	-1.30E-20	1.30E-06	3.00E-01	4.00E+00	50.0	-3.4
2.89E+18	-1.30E-20	1.30E-06	3.00E-01	4.00E+00	60.0	-3.7

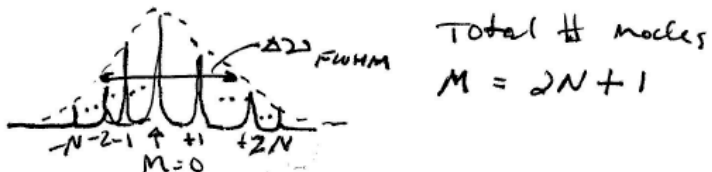


Problem 5:

For a mode-locked laser, assume the envelopes are given by the expression below and that the phases are equal. ν_m is the frequency spacing of mode m , where $m=0$ coincides with the central frequency of the atomic lineshape. Determine expressions for the mean power, peak power and pulse width (defined at the full-width half-maximum FWHM).

$$A_q = \sqrt{P} \frac{\left(\frac{\Delta\nu}{2}\right)^2}{(m\nu_m)^2 + \left(\frac{\Delta\nu}{2}\right)^2}, \quad m = -\infty, \dots, +\infty$$

Assume the gain curve and modes look something as follows



pulse width: The gain lineshape has a FWHM of $\Delta\nu$, so

$$\tau_{\text{pulse}} \approx \frac{1}{\Delta\nu}$$

Number of modes is given by mode separation ν_m and linewidth

$$M = \frac{\Delta\nu}{\nu_m}$$

mean intensity

$$\bar{I} = M |A|^2 = MP$$

peak intensity

$$I_p = M \bar{I} = M^2 P$$